THE JOINT HIGH \( Q_0 \) R&D PROGRAM FOR LCLS-II

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Abstract

The superconducting RF linac for LCLS-II calls for 1.3 GHz 9-cell cavities with an average intrinsic quality factor \( Q_0 \) of \( 2.7 \times 10^{10} \) at 2K and 16 MV/m accelerating gradient. A collaborative effort between Cornell University, FNAL, and JLab has been set up with the goal of developing and demonstrating a cavity treatment protocol for the LCLS-II cavities meeting these specifications. The high \( Q_0 \) treatment protocol is based on nitrogen doping of the RF surface layer during a high temperature heat treatment. This novel SRF cavity preparation was recently developed at FNAL and shown to result in SRF cavities of very high \( Q_0 \) at 2K with an increase in \( Q_0 \) from low to medium fields. N-doped single cell cavities at Cornell, FNAL, and JLab routinely exceed LCLS-II specification. 9-cell N-doped cavities at FNAL achieve an average \( Q_0 \)(T=2K, 16 MV/m) of \( \sim 3.4 \times 10^{10} \) with an average quench field of \( \sim 19 \) MV/m, meeting therefore overall with good margin the LCLS-II specification.

INTRODUCTION

The "Linac Coherent Light Source-II" Project will construct a 4 GeV CW superconducting linac in the first kilometer of the existing SLAC linac tunnel [1]. The new superconducting radio-frequency (SRF) linac will provide the electron beam for two new undulators, one optimized as a soft x-ray (200-1,300 eV) source, and the second providing 1-5 keV photons. First light from the new facility is expected in September 2019.

The LCLS-II baseline design calls for 1.3 GHz 9-cell cavities with an average intrinsic quality factor \( Q_0 \) of \( 2.7 \times 10^{10} \) at 2K and 16 MV/m accelerating gradient. High intrinsic quality factors are essential in keeping cryogenic infrastructure and operating cost within reasonable limits.

JOINT HIGH \( Q_0 \) R&D PROGRAM

The joint LCLS-II High \( Q_0 \) R&D effort aims to (a) establish a processing protocol suitable for production use which results in increased \( Q_0 \) values for 1.3 GHz superconducting cavities, operated at 2.0 K and (b) will establish a value of \( Q_0 \) that can be reliably demonstrated in a production acceptance testing setting. This R&D effort will also characterize the magnetic field environment required to preserve this performance in operational cryomodules and establish cavity optimal cool-down parameters. Success in the LCLS-II High \( Q_0 \) R&D program will lower the technical risk on the capacity of the cryoplant for the Project.

The recently-developed high \( Q_0 \) cavity surface processing recipe involving nitrogen-doping [2, 3] is an adaptation on internationally-recognized standard baseline recipes for producing high performance SRF cavities developed over the past decade. The LCLS-II High \( Q_0 \) R&D program will determine the small modifications that result in a realistic, industrial, cavity production process yielding high \( Q_0 \) that may then be applied to the fabrication and processing of LCLS-II cavities. The basic process adds \( \sim 20 \) mTorr nitrogen gas exposure at 800°C following the typical 800°C vacuum bake. After a light electropolish to remove surface nitrides that form, one is left with a surface that appears to be lightly doped with interstitial nitrogen and exhibits significantly reduced RF surface resistance compare with prior methods.

In CY2014, LCLS-II began funding work in the partner labs (Cornell, FNAL, and JLab) in order to expedite the migration of this "High \( Q_0 \)" technique from the lab to an element within a robust production process to be specified for use in LCLS-II construction.

Obtaining the highest \( Q_0 \) requires minimization of parasitic losses induced by the magnetic field environment present during cool-down of the cavities. This implies a new level of scrutiny of the materials used in nearby test hardware and also the cool-down thermal dynamics that either generate and/or exclude magnetic flux from the cavity. Such flux generates residual losses and thus limits the realized \( Q_0 \).

The work has three elements: (1) rapid single-cell work to explore the parameter space and to qualify basic procedures, (2) treatment and testing of 9-cell cavities in isolation, typically in vertical test dewars, to demonstrate that the basic process may be extended to accelerator cavities, and (3) testing of 9-cell cavities in horizontal test cryostats that include ancillary coupler, tuning, and shielding hardware to evaluate the challenges of preserving the high \( Q_0 \) performance in realistic cryomodule configurations. The goals of this effort are to quickly establish the technical credibility and viability of exploiting this new high \( Q_0 \) protocol as a central design element for LCLS-II. A well-defined, commercially imple-
mentable protocol will be specified, and the performance obtained by using that protocol will be demonstrated.

**CURRENT STATUS**

**Single Cell R&D**

Single-cell work is currently ongoing at all three partner labs to optimize process parameters and qualify basic procedures and facilities.

**Cornell:** Three single-cell cavities fabricated at Cornell were given a nitrogen doping and different amounts of material removal. All three cavities showed excellent performance, exceeding LCLS-II specifications, with 2 K quality factors of $3.5 \times 10^{10}$ to $4.5 \times 10^{10}$ and quench fields up to 32 MV/m [4]; see Fig. 1. Material parameters extracted from surface impedance measurements show that the N-doping leads to RF surface layers with very small mean free paths ($\ell \sim 10$ nm), i.e. to a superconductor in the dirty limit.

A nitrogen-doped cavity and $120^\circ C$ baked cavity were cooled in uniform ambient magnetic field and their residual resistances were measured for a variety of different ambient fields and cool-down rates. It was found that the nitrogen-doped cavity was $\sim 3.6$ times more susceptible to residual losses from trapped flux than the $120^\circ C$ baked cavity [5].

**FNAL:** FNAL has up to today more than 40 tests of single-cell 1.3GHz cavities prepared via nitrogen doping under different partial pressure, duration and temperature regimes. A subset of the Q vs E performance obtained for these cavities is shown in Fig. 2, showing the systematic improvement of quality factors compared to standard surface treatments. Recently, FNAL nitrogen bake has evolved from a one step diffusion process, where the nitrogen supply and the high temperature were simultaneously shut off, to a two step diffusion process [6] to allow to flatten the ideal nitrogen concentration, which produces the higher quality factors, over a larger depth from the cavity surface. This is an important step towards the implementation of this technology on a large scale production, allowing to reduce the risk of spread in $Q_0$ values due to tolerances in material removal post gas bake. Another important achievement that came with the two steps diffusion implementation was the improvement of quench fields of nitrogen doped single cell cavities, which from a systematic barrier at 20.5 MV/m, moved to gradients in the range 25-30.5 MV/m.

**JLab:** JLab is implementing a structured study using a set of nine single-cell cavities in a two-dimensional parameter space assessment. Working from successful protocols identified by FNAL, JLab varies the N-dose time and EP removal amount in a matrixed manner using sets of three cavities in each operation. This will minimize systematic errors, exercise the JLab facilities in the same way intended for use with 9-cell cavities, and demonstrate useful windows for process parameter ranges. JLab built six new cavities for this program and has contributed three NP-funded cavities to attain the required complement. JLab also upgraded its cavity heat treatment furnace to enable the controlled gas introduction at temperature required to apply the nitrogen diffusion process. In order to clearly distinguish improvements in cavity intrinsic rf losses from other parasitic effects, JLab has reworked cavity test hardware with carefully minimized permeability materials and magnetic field monitoring specifically for this project. The first pass through the matrix of nine single-cell tests has been completed. This found reliable high $Q_0$ performance with 2 minute nitrogen gas exposure and 10 $\mu$m EP, with little sensitivity to post-gas exposure dwell time duration in the range of 10-30 minutes. The second pass has just begun. It will examine a second matrix of parameters starting from a 20 minute nitrogen gas exposure.

**9-cell Cavity Vertical Tests**

FNAL has now doped several 1.3 GHz 9-cell cavities with the scope of transferring the single cell processing technique to a nine cell structure and studying the ideal process parameters to meet LCLS-II specs for both Q and gradients. Table 1 summarizes the results obtained so far in terms of $Q_0$ and

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**Figure 2:** $2.0\, \text{K}\, Q_0$ vs Eacc performance for sample of FNAL single-cell N-doped cavities.
quench fields reached by the 9-cell cavities treated with different nitrogen treatments (duration) or same gas treatment but for sequential amount of material removal. Results so far show an average $Q_0(T=2K, 16 \text{ MV/m}) \sim 3.4 \times 10^{10}$ and average quench field of $\sim 19 \text{ MV/m}$, meeting therefore overall with good margin the LCLS-II specifications. Detailed analysis [7] shows that all the cavities are identical in terms of BCS surface resistance, showing $R_{\text{BCS}}(2K, 16 \text{ MV/m}) \sim 4 \text{ n}\Omega$, which is less than half of what is typically obtained with the $120^\circ \text{C}$ bake surface processing. It is important to notice that several additional tests have been performed to study the origin of the spread in residual resistance and two important things have been found: 1) the effect of using stainless steel flanges versus NbTi flanges adds $\sim 1.5 \text{ n}\Omega$ residual resistance; 2) the difference in residual resistance from cavity to cavity is always localized in the end cells. In all cavities the central seven cells show an average residual resistance of $\sim 1 \text{ n}\Omega$, while the end cells residual varies from 1 up to 10 nΩ, potentially due to higher remnant fields near the end cells. Another important milestone achieved at FNAL is the vertical test of a dressed high $Q_0$ cavity. Results shown in Fig. 3 show that post LHe tank welding the quality factor remained unchanged at $\sim 3.4 \times 10^{10}$ at 2K and 16 MV/m with fast cooling from 300K and 15K. A significant degradation in quality factor is observed in the dressed cavity if cooling is performed slowly through the normal conducting to superconducting transition, consistent with previous findings [8], indicating that particular attention will have to be paid to this phenomenon in the cooling procedure of LCLS-II cryomodules. Results are described more in detail in [9].

At JLab, a set of six 9-cell cavities has been received from FNAL and preparations for their initial processing has begun. JLab will process and test this set of 9-cell cavities using a candidate production-style process that folds the new N-doping elements into a standard baseline recipe.

Cornell has started processing three 9-cell cavities. In a first vertical test, a Cornell N-doped 9-cell cavity reached fields above 20 MV/m, with a BCS surface resistance of $\sim 4 \text{ n}\Omega$, consistent with FNAL results.

### 9-cell Horizontal Cryomodule Tests

Performance testing of 9-cell cavities in horizontal configuration with operationally realistic cryogenic, vacuum, RF, and mechanical interfaces is most representative of conditions intended within the finished LCLS-II cryomodules. CW RF testing on this platform is required to demonstrate control of all the factors which can affect the operational $Q_0$ of the SRF cavities once installed in a cryomodule, and also some of the other potential contributors to dynamic cryogenic load.

Fermilab’s Horizontal Test Stand (HTS) is currently upgraded to reduce the ambient magnetic field at the cavity location, and will be used to evaluate the performance of three dressed LCLS-II cavities during the second half of 2014.

Cornell’s unique one-cavity cryomodule (Horizontal-Test Cryomodule, HTC [10]) has been modified to host LCLS-II 9-cell cavities. The cross-section of the HTC very closely resembles that of the planned LCLS-II cryomodules, and therefore allows performance testing of the LCLS-II cavities under the most representative of conditions. Three LCLS-II HTC tests are planned for the second half of 2014.

### CONCLUSIONS AND OUTLOOK

The LCLS-II High $Q_0$ R&D effort at Cornell, FNAL, and JLab is well on its way towards establishing the technical credibility and viability of exploiting the new high $Q_0$ N-doping protocol as a central design element for LCLS-II. N-doped single cell cavities at all three partner labs routinely exceed LCLS-II specification. 9-cell N-doped cavities at FNAL achieve an average $Q_0(T=2K, 16 \text{ MV/m}) \sim 3.4 \times 10^{10}$ with an average quench field of $\sim 19 \text{ MV/m}$, meeting therefore overall with good margin the LCLS-II specification. Future work will focus on defining the “frozen LCLS-II” high $Q_0$ protocol, determining critical parameters, finishing the transfer of the process to 9-cell cavities, and conducting performance verification in horizontal tests to understand $Q_0$ preservation, obtain $Q_0$ data under cryomodule conditions, and develop optimized cool-down procedures.

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Table 1: Performance of FNAL N-doped 9-Cell Cavities

<table>
<thead>
<tr>
<th>Name</th>
<th>quench field [MV/m] (2K, 16 MV/m)</th>
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<tr>
<td>TB9AES011</td>
<td>22</td>
<td>$3.4 \times 10^{10}$</td>
</tr>
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<td>$4.5 \times 10^{10}$</td>
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<td>23</td>
<td>$4.2 \times 10^{10}$</td>
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</tr>
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</table>

Figure 3: 2K vertical test performance of FNAL first high $Q_0$ doped cavity before and after LHe tank welding.
REFERENCES


